

Notice of References Cited

Application/Control No.

09/913,990

Applicant(s)/Patent Under
Reexamination
WOMELSDORF ET AL.

Examiner

Daniel S. Metzmaier

Art Unit

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Page 1 of 1

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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.